74AUP1G32

Low-power 2-input OR-gate Rev. 5 — 28 June 2012

Product data sheet

General description 1.

The 74AUP1G32 provides the single 2-input OR function.

Schmitt-trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}.

The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. **Features and benefits**

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
 - ◆ JESD8-12 (0.8 V to 1.3 V)
 - ◆ JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - ◆ JESD8-5 (1.8 V to 2.7 V)
 - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



3. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | |
|-------------|-------------------|--------|--|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74AUP1G32GW | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 | | | | |
| 74AUP1G32GM | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm | SOT886 | | | | |
| 74AUP1G32GF | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm | SOT891 | | | | |
| 74AUP1G32GN | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm | SOT1115 | | | | |
| 74AUP1G32GS | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 \times 1.0 \times 0.35 mm | SOT1202 | | | | |
| 74AUP1G32GX | –40 °C to +125 °C | X2SON5 | X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8 \times 0.8 \times 0.35$ mm | SOT1226 | | | | |

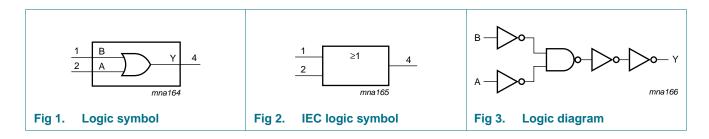
4. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| 74AUP1G32GW | pG |
| 74AUP1G32GM | pG |
| 74AUP1G32GF | pG |
| 74AUP1G32GN | pG |
| 74AUP1G32GS | pG |
| 74AUP1G32GX | pG |

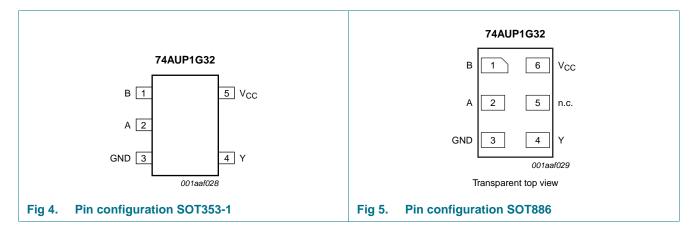
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

| Symbol | Pin | | Description |
|-----------------|-------------------|-------|----------------|
| | TSSOP5 and X2SON5 | XSON6 | |
| В | 1 | 1 | data input |
| Α | 2 | 2 | data input |
| GND | 3 | 3 | ground (0 V) |
| Υ | 4 | 4 | data output |
| n.c. | - | 5 | not connected |
| V _{CC} | 5 | 6 | supply voltage |

7. Functional description

Table 4. Function table[1]

| Input | | Output |
|-------|---|--------|
| Α | В | Υ |
| L | L | L |
| L | Н | Н |
| Н | L | Н |
| Н | Н | Н |

^[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|--|-------------------|------|------|
| V_{CC} | supply voltage | | -0.5 | +4.6 | V |
| I_{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| V_{I} | input voltage | | [<u>1</u>] -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| V_{O} | output voltage | Active mode and Power-down mode | [<u>1</u>] -0.5 | +4.6 | V |
| Io | output current | $V_O = 0 V \text{ to } V_{CC}$ | - | ±20 | mA |
| I _{CC} | supply current | | - | +50 | mA |
| I_{GND} | ground current | | -50 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ | [2] _ | 250 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------------------|--|-----|----------|------|
| V_{CC} | supply voltage | | 0.8 | 3.6 | V |
| V _I | input voltage | | 0 | 3.6 | V |
| Vo | output voltage | Active mode | 0 | V_{CC} | V |
| | | Power-down mode; $V_{CC} = 0 V$ | 0 | 3.6 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | 0 | 200 | ns/V |

^[2] For TSSOP5 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|---|---|----------------------|-----|----------------------|------|
| $T_{amb} = 2$ | 25 °C | | | | | |
| V_{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | $0.70 \times V_{CC}$ | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | $0.65 \times V_{CC}$ | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V_{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | $0.30 \times V_{CC}$ | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | $0.35 \times V_{CC}$ | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V}$ to 3.6 V | $V_{CC}-0.1$ | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.75 \times V_{CC}$ | - | - | V |
| | | $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 1.11 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.32 | - | - | V |
| | | $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 2.05 | - | - | V |
| | | $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.9 | - | - | V |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.72 | - | - | V |
| | | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.6 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | $I_O = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | - | - | $0.3 \times V_{CC}$ | V |
| | | $I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | - | - | 0.31 | V |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.31 | V |
| | | $I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.31 | V |
| | | $I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.44 | V |
| | | $I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.31 | V |
| | | $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.44 | V |
| I _I | input leakage current | $V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V | - | - | ±0.1 | μΑ |
| I _{OFF} | power-off leakage current | V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.2 | μΑ |
| ΔI_{OFF} | additional power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ±0.2 | μΑ |
| I _{CC} | supply current | V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.5 | μΑ |
| Δl _{CC} | additional supply current | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ | [1] - | - | 40 | μΑ |
| Cı | input capacitance | $V_{CC} = 0 \text{ V to } 3.6 \text{ V; } V_{I} = \text{GND or } V_{CC}$ | - | 1.5 | - | pF |
| C _O | output capacitance | $V_O = GND; V_{CC} = 0 V$ | - | 3 | - | pF |

 Table 7.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|--|----------------------|-----|----------------------|------|
| T _{amb} = - | 40 °C to +85 °C | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | $0.70 \times V_{CC}$ | - | - | V |
| | | V _{CC} = 0.9 V to 1.95 V | $0.65 \times V_{CC}$ | - | - | V |
| | | V _{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | $0.30 \times V_{CC}$ | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | $0.35 \times V_{CC}$ | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | - | - | 0.9 | V |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V}$ to 3.6 V | $V_{CC}-0.1$ | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.7 \times V_{CC}$ | - | - | V |
| | | $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 1.03 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.30 | - | - | V |
| | | $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.97 | - | - | V |
| | | $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.85 | - | - | V |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.67 | - | - | V |
| | | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.55 | - | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | $I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | - | - | $0.3 \times V_{CC}$ | V |
| | | $I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | - | - | 0.37 | V |
| | | $I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | - | - | 0.35 | V |
| | | I_{O} = 2.3 mA; V_{CC} = 2.3 V | - | - | 0.33 | V |
| | | $I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.45 | V |
| | | $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.33 | V |
| | | $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.45 | V |
| ļ | input leakage current | V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V | - | - | ±0.5 | μΑ |
| OFF | power-off leakage current | V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.5 | μΑ |
| Δl _{OFF} | additional power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ±0.6 | μΑ |
| CC | supply current | $V_1 = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.9 | μΑ |
| Δl _{CC} | additional supply current | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$ | [1] - | - | 50 | μΑ |

 Table 7.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Uni |
|----------------------|---|--|------------------------|-----|----------------------|-----|
| T _{amb} = - | 40 °C to +125 °C | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 0.8 V | $0.75 \times V_{CC}$ | - | - | ٧ |
| | | V _{CC} = 0.9 V to 1.95 V | $0.70 \times V_{CC}$ | - | - | V |
| | | V_{CC} = 2.3 V to 2.7 V | 1.6 | - | - | V |
| | | V_{CC} = 3.0 V to 3.6 V | 2.0 | - | - | V |
| √ _{IL} | LOW-level input voltage | V _{CC} = 0.8 V | - | - | $0.25 \times V_{CC}$ | V |
| | | V _{CC} = 0.9 V to 1.95 V | - | - | $0.30 \times V_{CC}$ | V |
| | | V _{CC} = 2.3 V to 2.7 V | - | - | 0.7 | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.9 | V |
| √oн | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_{O} = -20 \mu A$; $V_{CC} = 0.8 \text{ V}$ to 3.6 V | V _{CC} - 0.11 | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.6 \times V_{CC}$ | - | - | V |
| | | $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 0.93 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.17 | - | - | V |
| | | $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.77 | - | - | V |
| | | $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.67 | - | - | V |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.40 | - | - | V |
| | | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.30 | - | - | V |
| / _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.11 | V |
| | | $I_O = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | - | - | $0.33 \times V_{CC}$ | V |
| | | $I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | - | - | 0.41 | V |
| | | $I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | - | - | 0.39 | V |
| | | $I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.36 | V |
| | | $I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.50 | V |
| | | $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.36 | V |
| | | $I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.50 | V |
| I | input leakage current | $V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 V | - | - | ±0.75 | μΑ |
| OFF | power-off leakage current | V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.75 | μΑ |
| ∆l _{OFF} | additional power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ±0.75 | μΑ |
| СС | supply current | V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 1.4 | μΑ |
| 7l ^{CC} | additional supply current | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$ | [1] - | - | 75 | μΑ |

^[1] One input at V_{CC} – 0.6 V, other input at V_{CC} or GND.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

| Symbol | Parameter | Conditions | | Min | Typ 📶 | Max | Unit |
|-----------------------|----------------------------|--|-----|-----|-------|------|------|
| T _{amb} = 25 | °C; C _L = 5 pF | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | [2] | | | | |
| | | V _{CC} = 0.8 V | | - | 16.8 | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 2.4 | 5.1 | 10.9 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 1.6 | 3.6 | 6.6 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 1.4 | 3.0 | 5.2 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 1.1 | 2.4 | 3.9 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 1.0 | 2.1 | 3.5 | ns |
| T _{amb} = 25 | °C; C _L = 10 pF | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | [2] | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | | - | 20.3 | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 2.3 | 5.9 | 12.7 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 1.9 | 4.2 | 7.7 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 1.7 | 3.5 | 6.0 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 1.4 | 2.9 | 4.6 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 1.3 | 2.7 | 4.3 | ns |
| T _{amb} = 25 | °C; C _L = 15 pF | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | [2] | | | | |
| | | V _{CC} = 0.8 V | | - | 23.8 | - | ns |
| | | V _{CC} = 1.1 V to 1.3 V | | 3.3 | 6.7 | 14.3 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 2.3 | 4.8 | 8.6 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | | 2.0 | 4.0 | 6.7 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 1.7 | 3.3 | 5.3 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 1.5 | 3.1 | 4.9 | ns |
| T _{amb} = 25 | °C; C _L = 30 pF | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | [2] | | | | |
| | | V _{CC} = 0.8 V | | - | 34.1 | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 4.5 | 9.0 | 19.1 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 3.4 | 6.3 | 11.3 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.6 | 5.3 | 8.9 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 2.3 | 4.4 | 7.0 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 2.2 | 4.2 | 6.4 | ns |

 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

| Symbol | Parameter | Conditions | Min | Typ 🗓 | Max | Unit |
|-----------------------|-------------------------------|--|-----|-------|-----|------|
| T _{amb} = 25 | °C | | | | | |
| C_{PD} | power dissipation capacitance | $f = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ | [3] | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | - | 2.5 | - | pF |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | - | 2.6 | - | pF |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | - | 2.8 | - | pF |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | - | 2.9 | - | pF |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | 3.4 | - | pF |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | - | 3.9 | - | pF |

^[1] All typical values are measured at nominal V_{CC} .

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

| Symbol | Parameter | Conditions | | –40 °C t | o +85 °C | -40 °C to | +125 °C | Unit |
|------------------------|-------------------|--|------------|----------|----------|-----------|---------|------|
| | | | | Min | Max | Min | Max | |
| $C_L = 5 pF$ | | | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | <u>[1]</u> | | | | | |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 2.1 | 11.9 | 2.1 | 13.2 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 1.4 | 7.5 | 1.4 | 8.3 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 1.2 | 6.0 | 1.2 | 6.6 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 1.0 | 4.6 | 1.0 | 5.1 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 0.9 | 4.1 | 0.9 | 4.6 | ns |
| C _L = 10 pF | | | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | <u>[1]</u> | | | | | |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 2.1 | 13.8 | 2.1 | 15.2 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 1.7 | 8.7 | 1.7 | 9.6 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 1.5 | 6.9 | 1.5 | 7.7 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 1.3 | 5.5 | 1.3 | 6.1 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 1.2 | 5.0 | 1.2 | 5.5 | ns |

^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 Table 9.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9

| Symbol | Parameter | Conditions | | –40 °C t | o +85 °C | -40 °C to | Unit | |
|------------------------|-------------------|--|-----|----------|----------|-----------|------|----|
| | | | | Min | Max | Min | Max | |
| C _L = 15 pF | | | ' | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | [1] | | | | | |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 3.0 | 15.6 | 3.0 | 17.2 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 2.0 | 9.8 | 2.0 | 10.8 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 1.8 | 7.9 | 1.8 | 8.7 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 1.6 | 6.3 | 1.6 | 6.9 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 1.5 | 5.8 | 1.5 | 6.4 | ns |
| $C_L = 30 pF$ | • | | | | | | | |
| t _{pd} | propagation delay | A, B to Y; see Figure 8 | [1] | | | | | |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | 4.0 | 21.5 | 4.0 | 23.7 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | 2.9 | 13.3 | 2.9 | 14.7 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | | 2.4 | 10.7 | 2.4 | 11.8 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | 2.2 | 8.4 | 2.2 | 9.3 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | 2.1 | 7.7 | 2.1 | 8.5 | ns |

^[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

12. Waveforms

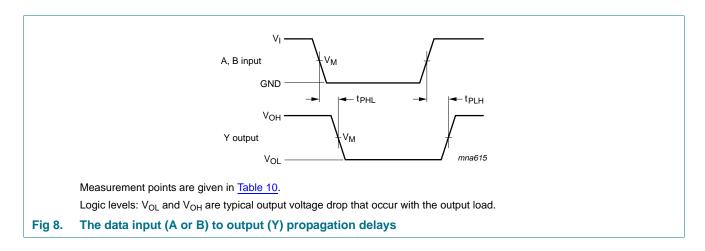
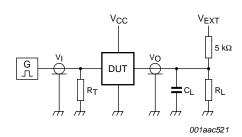


Table 10. Measurement points

| Supply voltage | Output | Input | | |
|-----------------|---------------------|---------------------|-----------------|-------------|
| V _{CC} | V _M | V _M | V _I | $t_r = t_f$ |
| 0.8 V to 3.6 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | V _{CC} | ≤ 3.0 ns |



Test data is given in Table 11.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

Table 11. Test data

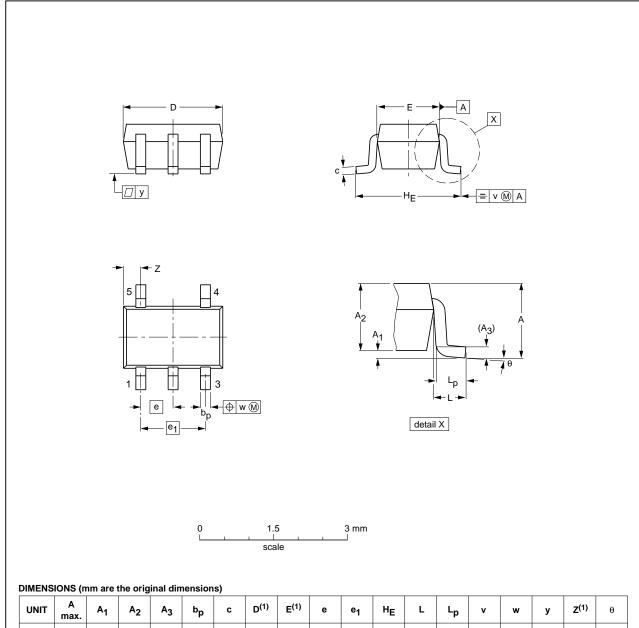
| Supply voltage | Load | | V _{EXT} | | | | |
|-----------------|------------------------------|------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|--|--|
| V _{CC} | CL | R _L [1] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | | |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 k Ω or 1 M Ω | open | GND | $2\times V_{CC}$ | | |

[1] For measuring enable and disable times R_L = 5 k Ω , for measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | е | e ₁ | HE | L | Lp | v | w | у | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|--------------|--------------|------------------|------------------|------|----------------|-------------|-------|--------------|-----|-----|-----|------------------|----------|
| mm | 1.1 | 0.1 0 | 1.0 0.8 | 0.15 | 0.30 0.15 | 0.25 0.08 | 2.25 1.85 | 1.35 1.15 | 0.65 | 1.3 | 2.25 2.0 | 0.425 | 0.46 0.21 | 0.3 | 0.1 | 0.1 | 0.60 0.15 | 7° 0° |

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE | | | REFER | EUROPEAN | ISSUE DATE | | |
|---------|--|-----|--------|----------|------------|------------|----------------------------------|
| VERSION | | IEC | JEDEC | JEITA | | PROJECTION | 1330E DATE |
| SOT353- | | | MO-203 | SC-88A | | | -00-09-01 03-02-19 |

Fig 10. Package outline SOT353-1 (TSSOP5)

74AUP1G32

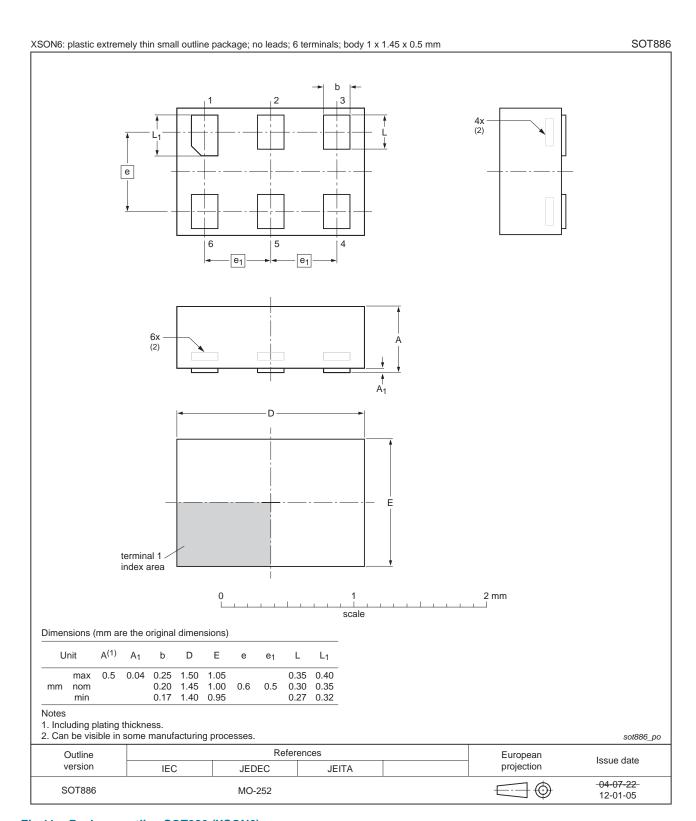


Fig 11. Package outline SOT886 (XSON6)

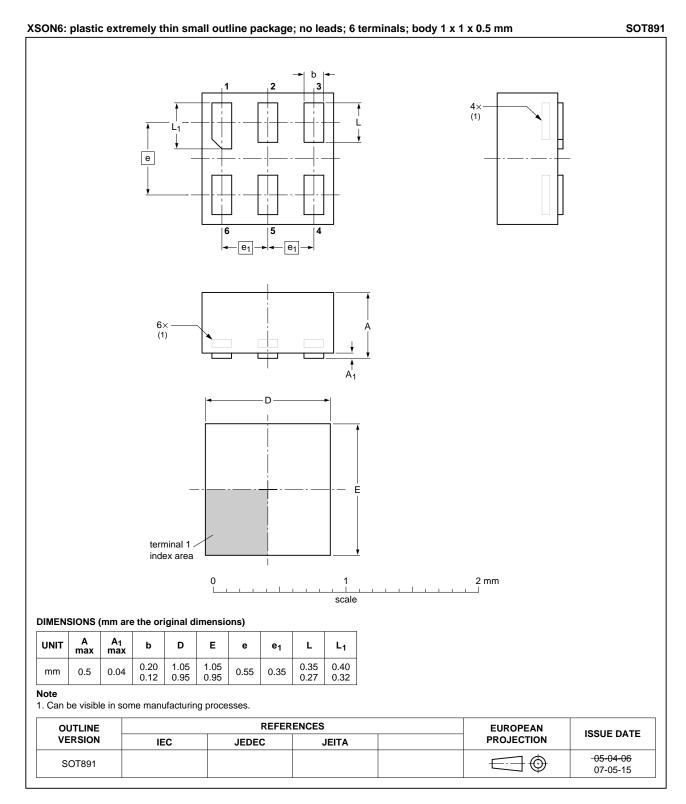


Fig 12. Package outline SOT891 (XSON6)

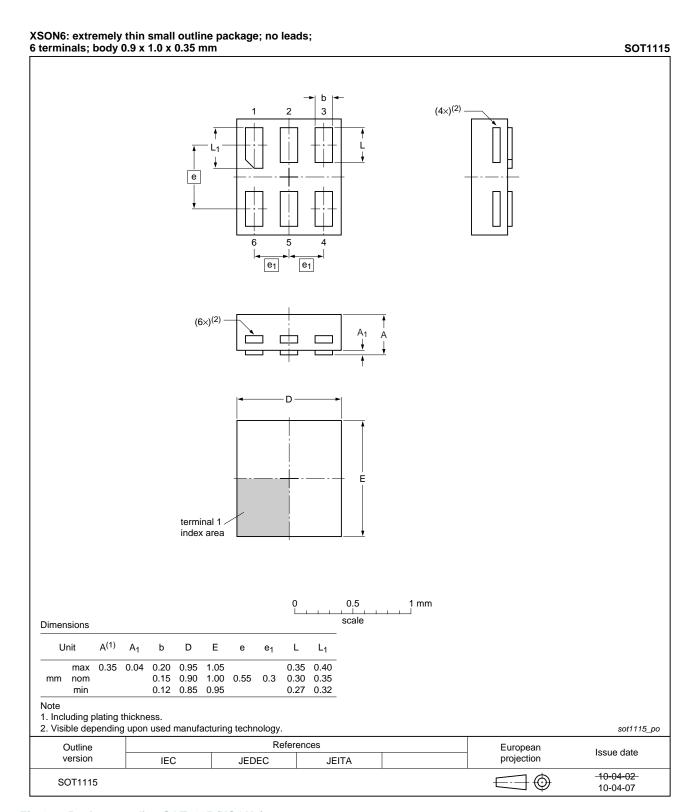


Fig 13. Package outline SOT1115 (XSON6)

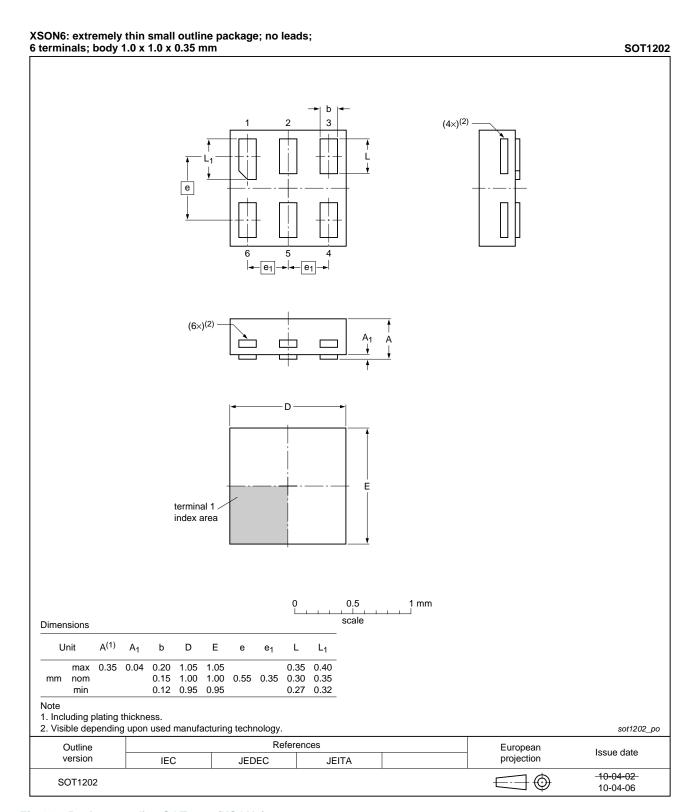


Fig 14. Package outline SOT1202 (XSON6)

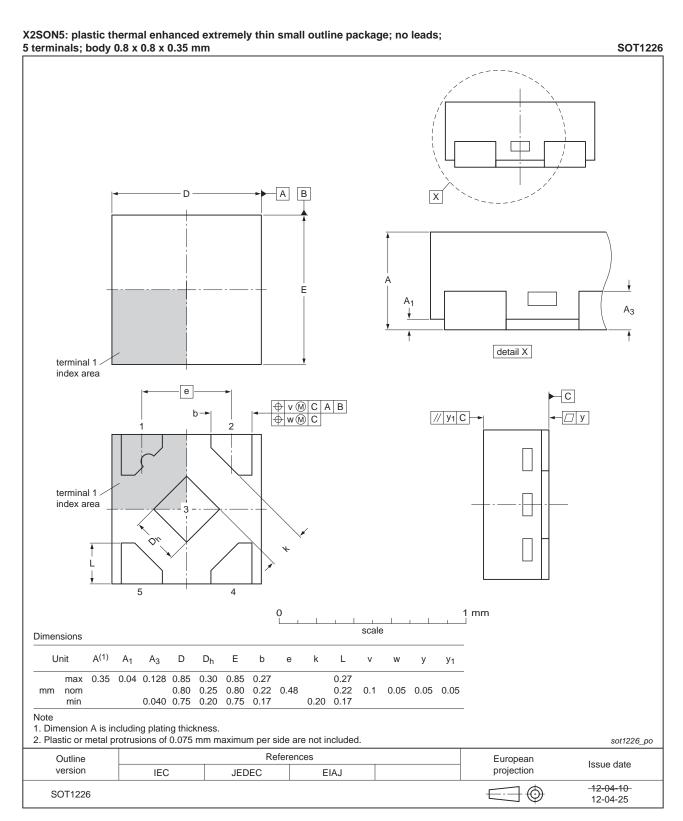


Fig 15. Package outline SOT1226 (X2SON5)

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Product data sheet

14. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| MM | Machine Model |

15. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|----------------------------------|--------------------------------------|------------------|---------------|
| 74AUP1G32 v.5 | 20120628 | Product data sheet | - | 74AUP1G32 v.4 |
| Modifications: | Added type r | number 74AUP1G32GX (SOT | 1226) | |
| | Package out | line drawing of SOT886 (<u>Figu</u> | re 11) modified. | |
| 74AUP1G32 v.4 | 20111123 | Product data sheet | - | 74AUP1G32 v.3 |
| Modifications: | Legal pages | updated. | | |
| 74AUP1G32 v.3 | 20101012 | Product data sheet | - | 74AUP1G32 v.2 |
| 74AUP1G32 v.2 | 20060721 | Product data sheet | - | 74AUP1G32 v.1 |
| 74AUP1G32 v.1 | 20050802 | Product data sheet | - | - |
| | | | | |

16. Legal information

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| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Low-power 2-input OR-gate

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